NSN 5961-01-301-4750

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Inclosure Material:

Metal

Overall Length:

5.3 millimeters

Terminal Length:

12.7 millimeters

Overall Diameter:

4.8 millimeters

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-72

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

30.0 drain to substrate voltage and 30.0 source to substrate voltage and 10.0 gate to substrate voltage

Current Rating Per Characteristic:

25.00 milliamperes drain current and 50.00 milliamperes source current

Power Rating Per Characteristic:

200.0 milliwatts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Terminal Type And Quantity:

4 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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